TOSHIBA Multi-Chip Transistor Silicon NPN Epitaxial Type

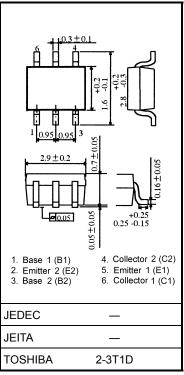
TPC6701

High-Speed Switching Applications Motor Drive Applications Inverter Lighting Applications

- Two NPN transistors are mounted on a compact and slim package.
- High DC current gain: h_{FE} = 400 to 1000 (I_C = 0.1 A)
- Low collector-emitter saturation voltage: V_{CE} (sat) = 0.17 V (max)
- High-speed switching: $t_f = 85 \text{ ns}$ (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	100	V	
Collector-emitter voltage		VCEX	80	V	
Collector-emitter voltage		VCEO	50	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	۱ _C	1.0	Α	
	Pulse	I _{CP}	2.0	А	
Base current		Ι _Β	0.1	mA	
Collector power dissipation (single-device operation)		PC	400	mW	
		(Note 1)	400	THVV	
Total collector power dissipation (simultaneous operation)		P _{CT}	660	mW	
		(Note 2)	000		
Thermal resistance, junction to ambient (single-device operation)		R _{th (j-a)}	312	°C/W	
		(Note 1)	512	0/00	
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.011 g (typ.)

Note 1: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

Note 2: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²) Total collector power dissipation value when two devices are operated at the same time

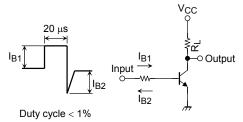
Note 3: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

Electrical Characteristics (Ta = 25°C)

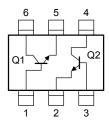
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	$V_{CB} = 100 \ V, \ I_E = 0$		_	100	nA
Emitter cut-off current		I _{EBO}	$V_{EB}=7~V,~I_C=0$	_		100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	50		_	V
DC current gain		h _{FE} (1)	$V_{CE} = 2 V, I_C = 0.1 A$	400		1000	
		h _{FE} (2)	$V_{CE} = 2 V, I_C = 0.3 A$	200		_	
Collector-emitter saturation voltage		V _{CE (sat)}	$I_C = 300 \text{ mA}, I_B = 6 \text{ mA}$			0.17	V
Base-emitter saturation voltage		V _{BE (sat)}	$I_C = 300 \text{ mA}, I_B = 6 \text{ mA}$			1.10	V
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		5	_	pF
Switching time	Rise time	tr	See Figure 1 circuit diagram.		35		
	Storage time	t _{stg}	V _{CC} ≈ 30 V, R _L = 100 Ω		680		ns
	Fall time	t _f	$I_{B1} = -I_{B2} = 10 \text{ mA}$		85		

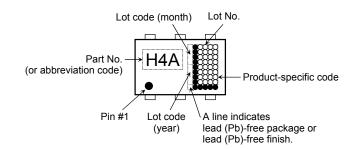




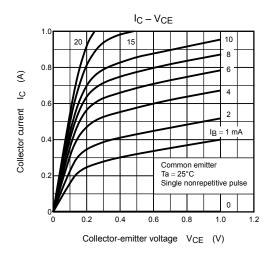
Circuit Configuration

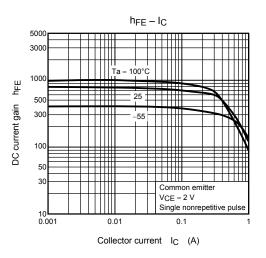
Marking

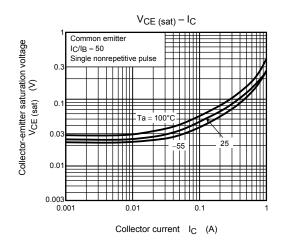


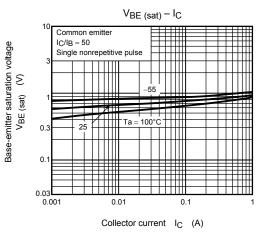


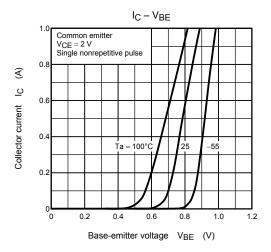
TOSHIBA

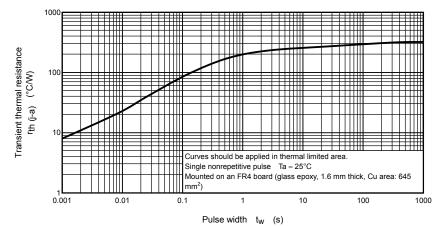












Transient Thermal Resistance $r_{th} - t_w$

Safe Operating Area 10 1 ms* 100 µs* IC max (pulsed)* 10 ms* 10 μs³ IC max (puised) € 10 s* <u>ں</u> $\overline{}$ Collector current DC operation 0.1 (Ta = 25°C) *: Single nonrepetitive pulse Ta = 25°C Note that the curves for 100 ms, 10 s and DC operation will be different when the devices aren't mounted on an FR4 board (glass epoxy, 1,6 mm thick, Cu area: 645 mm²). Single-device operation These characteristic curves must be derated linearly with increase in temperature. 0.01 max VCEO in temperature. 0.001 0.1 1 10 100 Collector-emitter voltage V_{CE} (V)

Simultaneous Operation 0.5 Permissible power dissipation for Q2 PC (W) 0.4 0.3 0.2 DC operation 0.1 Ta = 25°C Mounted on an FR4 board (glass epoxy 1.6 mm thick, Cu area: 645 mm²) 0 0.1 0.2 0.3 0.5 0.4 0 Permissible power dissipation for Q1 PC (W)

Permissible Power Dissipation for

RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer's own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which
 may result from its use. No license is granted by implication or otherwise under any patents or other rights of
 TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.